# 2SC3413

Silicon NPN Epitaxial

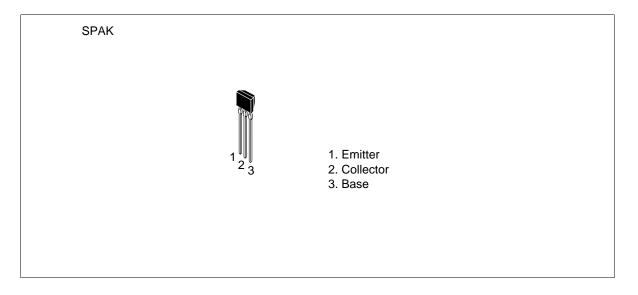
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ADE-208-1085 (Z) 1st. Edition Mar. 2001

### Application

- Low frequency low noise amplifier
- HF amplifier

#### Outline





## 2<u>SC3413</u>

## **Absolute Maximum Ratings** (Ta = 25°C)

Item	Symbol	Ratings	Unit	
Collector to base voltage	V <sub>CBO</sub>	40	V	
Collector to emitter voltage	V <sub>CEO</sub>	30	V	
Emitter to base voltage	V <sub>EBO</sub>	5	V	
Collector current	Ι <sub>c</sub>	100	mA	
Collector power dissipation	Pc	300	mW	
Junction temperature	Tj	150	°C	
Storage temperature	Tstg	-55 to +150	°C	

#### **Electrical Characteristics** (Ta = 25°C)

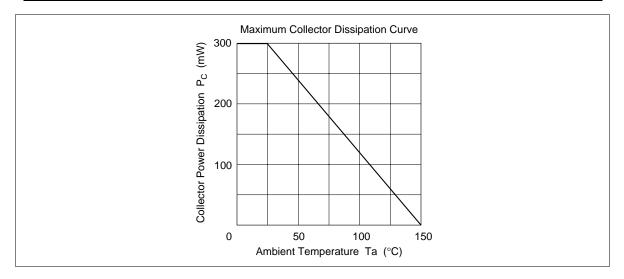
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(\text{BR})\text{CBO}}$	40	_	_	V	$I_{c} = 10 \ \mu A, \ I_{E} = 0$
Collector to emitter breakdown voltage	$V_{(\text{BR})\text{CEO}}$	30	—	_	V	$I_c = 1 \text{ mA}, \text{ R}_{BE} = \infty$
Emitter to base breakdown voltage	$V_{(BR)EBO}$	5	—	—	V	$I_{\rm E} = 10 \ \mu A, \ I_{\rm C} = 0$
Collector cutoff current	I <sub>CBO</sub>	_	_	0.5	μΑ	$V_{CB} = 18 \text{ V}, I_{E} = 0$
Emitter cutoff current	I <sub>EBO</sub>	_		0.5	μA	$V_{EB} = 2 V, I_{C} = 0$
DC current transfer ratio	$h_{\rm FE}^{*1}$	100	_	500		$V_{ce} = 12 \text{ V}, \text{ I}_{c} = 2 \text{ mA}$
Base to emitter voltage	V <sub>BE</sub>	_		0.75	V	$V_{ce} = 12 \text{ V}, \text{ I}_{c} = 2 \text{ mA}$
Collector to emitter saturation voltage	$V_{\text{CE(sat)}}$	—	—	0.2	V	$I_{c} = 10 \text{ mA}, I_{B} = 1 \text{ mA}$
Gain bandwidth product	f <sub>T</sub>	_	200	_	MHz	$V_{ce} = 12 \text{ V}, \text{ I}_{c} = 2 \text{ mA}$
Collector output capacitance	Cob	_		3.5	pF	V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0, f = 1 MHz
Noise figure	NF	—	1.0	5.0	dB	$V_{ce} = 6 \text{ V}, \text{ I}_c = 0.1 \text{ mA},$ $R_g = 1  k\Omega, \text{ f} = 1    \text{Hz}$
Note: 1. The 2SC3413 is gro   B C D	uped by h <sub>F</sub>	<sub>e</sub> as follo	ows.			

100 to 200 160 to 320 250 to 500

See characteristic curves of 2SC458(LG).

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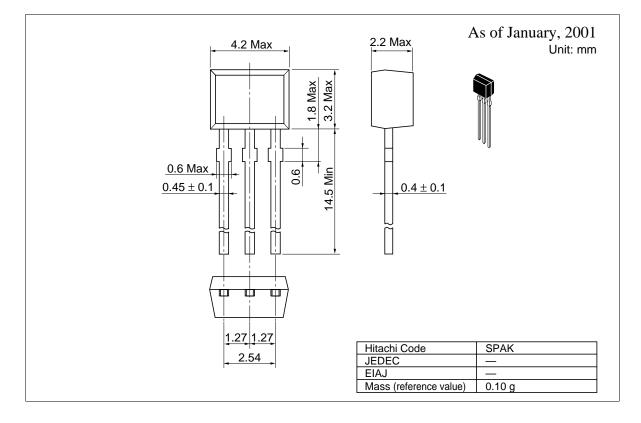
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### **Package Dimensions**



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